# 5.5V 4A Load Switch with Reverse Current Protection and Controlled Turn On

### **General Description**

The ET3565 is a small, ultra-low  $R_{ON}$  load switch with controlled turn on. The device contains a low  $R_{ON}$  N-Channel MOSFET that can operate over an input voltage range of 1 V to 5.5 V and switch currents of up to 4 A. An integrated charge pump biases the NMOS switch in order to achieve a low switch ON-Resistance. The switch is controlled by an on/off input (ON), which is capable of interfacing directly with low-voltage GPIO control signals. The rise time of the ET3565 device is internally controlled in order to avoid inrush current.

The ET3565 provides reverse current protection. When the power switch is disabled, the device will not allow the flow of current towards the input side of the switch. The reverse current protection feature is active only when the device is disabled so as to allow for intentional reverse current (when the switch is enabled) for some applications.

The ET3565 is available in a small, space-saving WLCSP6 package and is characterized for operation over the free air temperature range of -40°C to 85°C.

### Features

- Integrated N-MOSFET Load Switch
- Input Voltage Range: 1.0V to 5.5V
- Ultra-Low On-Resistance
  - --  $R_{ON}$  = 17.5m $\Omega$  @ V<sub>IN</sub> = 3.3V
- Reverse Current Protection (When Disabled)
- Low Shutdown Current: 135nA (TYP)
- Low Threshold 1.2V GPIO Control Input
- Controlled Slew Rate to Avoid Inrush Current
- Bi-directional Power Supplier for Power Zone Application
- Part No. and Package

Part No.	Package	MSL
ET3565	WLCSP6 (1.36mm*0.86mm*0.55mm)	Level 1

### Applications

- Smartphone
- Notebook Computer and Ultra-book
- Tablet PC Computer
- Solid State Drive (SSD)
- DTV/IP Set Top Box
- POS Terminal and Media Gateway

## ET3565

### **Pin Configuration**



### **Pin Function**

Pin Name	Symbol	Pin Description		
A1, B1	VOUT	Switch Output.		
A2, B2	VIN	Switch Input. Use a bypass capacitor (ceramic) to ground.		
C1	GND	Ground.		
C2	ON	Switch Control Input. Do not float this pin. Logic high turns on power switch		

### **Block Diagram**



### **Functional Description**

#### **ON/OFF** Control

The ON pin controls the switch. The ON pin is compatible with standard GPIO logic threshold. It can be used with any micro-controller with 1.2V,1.8V,2.5V,3.3V or 5.5V GPIO.

#### Table 1. Function Table

On State	V <sub>IN</sub> to V <sub>OUT</sub>
L	Off
Н	On

#### **Reverse Current Protection**

The reverse current protection feature prevents the current to flow from  $V_{OUT}$  to  $V_{IN}$  when ET3565 are disabled. This feature is particularly useful when the outputs of ET3565 need to be driven by another voltage source after ET3565 are disabled (for example in a power multiplexer application).

In order for this feature to work, ET3565 have to be disabled and either of the following conditions shall be met:  $V_{IN} > 1V$  or  $V_{OUT} > 1V$ .

### **Application Information**

#### Input Capacitor

It is recommended to place a capacitor ( $C_{IN}$ ) between VIN and GND pins of ET3565. This capacitor helps to limit the voltage drop on the input voltage supply when the switch turns ON into a discharged load capacitor. A 1µF ceramic capacitor that is placed close to the IC pins is usually sufficient. Higher values of  $C_{IN}$  can be used to further reduce the voltage drop in high current applications.

### **Output Capacitor**

It is recommended to place a capacitor ( $C_{OUT}$ ) between VOUT and GND pins of ET3565. This capacitor acts as a low pass filter along with the switch ON-resistance to remove any voltage glitches coming from the input voltage source. It is generally recommended to have  $C_{IN}$  greater than  $C_{OUT}$  so that once the switch is turned ON,  $C_{OUT}$  can charge up to  $V_{IN}$  without  $V_{IN}$  dropping significantly. A 0.1µF ceramic capacitor that is placed close to the IC pins is usually sufficient.

### **Standby Power Reduction**



## ET3565

Any end equipment that is being powered from the battery has a need to reduce current consumption in order to keep the battery charged for a longer time. ET3565 helps to accomplish this by turning off the supply to the modules that are in standby state and hence significantly reduces the leakage current overhead of the standby modules, shows in Fig3.



Power Supply Sequencing Without a GPIO Input

In many end equipment, there is a need to power up various modules in a predetermined manner. ET3565 can solve the problem of power sequencing without adding any complexity to the overall system. Fig4 shows the configuration required for powering up two modules in a fixed sequence. The output of the first load switch is tied to the enable of the second load switch, so when Module 1 is powered the second load switch is enabled and Module 2 is powered.

### **Typical Application**

ET3565 is an ultra-low ON-resistance, 4A integrated load switch that is capable of interfacing directly with 1S battery in portable consumer devices such as smartphones, tablets etc. Its wide input voltage range (1 V to 5.5 V) makes it suitable to be used for lower voltage rails as well inside different end equipments to accomplish power sequencing, inrush current control and reducing leakage current in subsystems that are in standby mode.

Fig 5 shows the typical application circuit of ET3565.



### Power Supply Recommendations

The device is designed to operate with a V<sub>IN</sub> range of 1 V to 5.5 V. This supply must be well regulated and placed as close to the device terminal as possible with the recommended 1  $\mu$ F bypass capacitor.

If the supply is located more than a few inches from the device terminals, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. If additional bulk capacitance is required, an electrolytic, tantalum, or ceramic capacitor of 10 µF may be sufficient.

### Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
V <sub>IN</sub>	Input voltage range	-0.3 to 6.0	V
Vout	Output voltage range	-0.3 to 6.0	V
Von	ON pin voltage range	-0.3 to 6.0	V
Імах	Maximum continuous switch current	4	A
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage temperature range	-65 to 150	°C
Tslod	Lead Temperature (Soldering, 10 sec)	300	°C
R <sub>0JA</sub>	Thermal Resistance, Junction-to-Air	83	°C/W
	Human Body Model (JESD22-A114)	±4.0KV	V
ESD	Charged Device Model (JESD22-C101)	±1.5KV	V
Lu	Latch Up(EIA/JESD78E)	±200	mA

Over operating free-air temperature range (unless otherwise noted)

### **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Unit
VIN	Input voltage range	1.0	5.5	V
Vout	Output voltage range	0	5.5	V
V <sub>ON</sub>	ON pin voltage range	0	V <sub>IN</sub>	V
TA	Operating free air temperature range	-40	85	°C
C <sub>IN</sub>	Input capacitor	1 <sup>(1)</sup>		uF

*Note1:* Refer to the application section.

## **Electrical Characteristics**

0	Demonster	O an all the sec	T <sub>A</sub> = +25°C			11	
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
VIN	Input Voltage Range		1.0 <sup>(2)</sup>		5.5	V	
		I <sub>OUT</sub> = 0, V <sub>ON</sub> = V <sub>IN</sub> = 5.5V,T <sub>A</sub> = +25°C		0.510	1.0		
		I <sub>OUT</sub> = 0, V <sub>ON</sub> = V <sub>IN</sub> = 5.0V, T <sub>A</sub> = +25°C		0.460	1.0		
		$I_{OUT} = 0, V_{ON} = V_{IN} = 4.5V, T_A = +25^{\circ}C$		0.380	1.0		
	Quiescent Current	$I_{OUT} = 0, V_{ON} = V_{IN} = 3.3V, T_A = +25^{\circ}C$		0.325	1.0		
$I_{Q_VIN}$		I <sub>OUT</sub> = 0, V <sub>ON</sub> = V <sub>IN</sub> = 2.5V,T <sub>A</sub> = +25°C		0.290	1.0	μA	
		$I_{OUT} = 0$ , $V_{ON} = V_{IN} = 1.8V$ , $T_A = +25^{\circ}C$		0.265	1.0		
		I <sub>OUT</sub> = 0, V <sub>ON</sub> = V <sub>IN</sub> = 1.2V,T <sub>A</sub> = +25°C		0.220	1.0		
		$I_{OUT} = 0$ , $V_{ON} = V_{IN} = 1.0V$ , $T_A = +25^{\circ}C$		0.175	1.0		
	Shutdown Current	$V_{ON} = 0V, V_{IN} = 5.5V, V_{OUT} = 0V, T_A = 25^{\circ}C$		0.135	0.5	— μΑ	
Isd_vin		V <sub>ON</sub> = 0V, V <sub>IN</sub> = 1V, V <sub>OUT</sub> = 0V, T <sub>A</sub> = +25°C		0.022	0.5		
	On-Resistance	V <sub>IN</sub> = 5.5V, I <sub>OUT</sub> = -200mA	8.5	17.0	26	- mΩ	
Ron		V <sub>IN</sub> = 3.3V, I <sub>OUT</sub> = -200mA	9.0	17.5	28		
RON		V <sub>IN</sub> = 1.8V, I <sub>OUT</sub> = -200mA	10.0	18.0	30		
		V <sub>IN</sub> = 1.0V, I <sub>OUT</sub> = -200mA	12.0	24.0	40		
VIH	ON High-level ON voltage	$V_{IN}$ = 1.0V to 5.5 V	0.9			v	
VIL	ON Low-level V <sub>IN</sub> = 1.0V to 5.5 V				0.4	v	
Ion	ON Pin Leakage Current	$V_{ON}$ = 1.0V to 5.0V, $V_{IN}$ = 5.5V		2	150	nA	
I <sub>RC_VOUT</sub>	Reverse Current When Disabled	V <sub>ON</sub> = 0V, V <sub>IN</sub> =3.0V, V <sub>OUT</sub> = 3.8V		0.07	1.0	μA	

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	lical values	arearia	- <del>+</del> ZƏ (J.	$\mathbf{v}$ in $-\mathbf{i}$	10 5.5 V.	umess	omerwise	noted.)

*Note2:* When  $V_{IN} < 1.5V$ , we suggest to set  $V_{ON} \ge 1.5V$ , which can reduce  $R_{ON}$ .

## **Switching Characteristics**

Parameter		Conditions	٦	T <sub>A</sub> =+25°C		
		Conditions	Min	Тур	Max	Unit
V <sub>IN</sub> = 5.0\	/,T <sub>A</sub> = +25°C, unless ot	herwise noted.				
ton	Turn-On Time	Rout = 10Ω, CIN = 1μF, Cout = 0.1μF	1200	1700	2200	
toff	Turn-Off Time	R <sub>OUT</sub> = 10Ω, C <sub>IN</sub> = 1μF, C <sub>OUT</sub> = 0.1μF	3	10	20	
t <sub>R</sub>	Vout Rise Time	Rout = 10Ω, C <sub>IN</sub> = 1μF, C <sub>OUT</sub> = 0.1μF	900	1400	2100	μs
t⊧	Vout Fall Time	Rout = 10Ω, CIN = 1μF, Cout = 0.1μF	0.5	2.1	10	
t <sub>D</sub>	Delay Time	$R_{OUT} = 10\Omega, C_{IN} = 1\mu F, C_{OUT} = 0.1\mu F$	800	1300	1800	
V <sub>IN</sub> = 3.3\	/,T <sub>A</sub> = +25°C, unless ot	herwise noted.				•
t <sub>ON</sub>	Turn-On Time	$R_{OUT}$ = 10 $\Omega$ , $C_{IN}$ = 1 $\mu$ F, $C_{OUT}$ = 0.1 $\mu$ F	1100	1600	2100	
toff	Turn-Off Time	R <sub>OUT</sub> = 10Ω, C <sub>IN</sub> = 1μF, C <sub>OUT</sub> = 0.1μF	3	10	20	
t <sub>R</sub>	Vout Rise Time	Rout = 10Ω, C <sub>IN</sub> = 1μF, C <sub>OUT</sub> = 0.1μF	800	1300	2000	μs
t⊧	Vout Fall Time	Rout = 10Ω, CIN = 1μF, Cout = 0.1μF	0.5	2.1	10	
t <sub>D</sub>	Delay Time	$R_{OUT} = 10\Omega$ , $C_{IN} = 1\mu$ F, $C_{OUT} = 0.1\mu$ F	600	1100	1600	
V <sub>IN</sub> = 1.8\	/,T <sub>A</sub> = +25°C, unless ot	herwise noted.				
t <sub>ON</sub>	Turn-On Time	$R_{OUT}$ = 10 $\Omega$ , $C_{IN}$ = 1 $\mu$ F, $C_{OUT}$ = 0.1 $\mu$ F	750	1500	2250	
toff	Turn-Off Time	Rout = 10Ω, Cin = 1μF, Cout = 0.1μF	3	10	20	
t <sub>R</sub>	Vout Rise Time	Rout = 10Ω, CIN = 1μF, Cout = 0.1μF	600	1100	1800	μs
t⊧	Vout Fall Time	Rout = 10Ω, CIN = 1μF, COUT = 0.1μF	0.5	2	10	
t <sub>D</sub>	Delay Time	$R_{OUT} = 10\Omega, C_{IN} = 1\mu F, C_{OUT} = 0.1\mu F$	600	1100	1600	
V <sub>IN</sub> = 1.2\	/,T <sub>A</sub> = +25°C, unless ot	herwise noted.	•		•	
t <sub>ON</sub>	Turn-On Time	$R_{OUT} = 10\Omega, C_{IN} = 1\mu F, C_{OUT} = 0.1\mu F$	750	1500	2250	
toff	Turn-Off Time	R <sub>OUT</sub> = 10Ω, C <sub>IN</sub> = 1μF, C <sub>OUT</sub> = 0.1μF	3	10	20	
t <sub>R</sub>	Vout Rise Time	R <sub>OUT</sub> = 10Ω, C <sub>IN</sub> = 1μF, C <sub>OUT</sub> = 0.1μF	1200	2100	2800	μs
t⊧	Vout Fall Time	Rout = 10Ω, CIN = 1μF, Cout = 0.1μF	0.5	2	10	
t⊳	Delay Time	$R_{OUT} = 10\Omega, C_{IN} = 1\mu F, C_{OUT} = 0.1\mu F$	700	1200	1700	

## **Typical Characteristics**



## Package Dimension

WLCSP6 (1.36mm×0.86mm)





### Dimensions Table (Units: mm)

Symbol	Min	Nom	Мах	
А	0.52	0.55	0.58	
A1	0.175	0.195	0.215	
A2	0.340	0.355	0.370	
b	0.245	0.265	0.285	
D	0.84	0.86	0.88	
E	1.34	1.36	1.38	
е	0.500BSC			

## ET3565

### Таре



## Marking



## **Revision History and Checking Table**

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2022-02-11	Preliminary Version	Wuxj	Wuxj	Liujy
0.1	2023-11-08	Update Format	Wangar Shibo	Tugz	Liujy
0.2	2024-01-24	Add SPEC & Tape & Marking	Tugz	Luh	Liujy
1.0	2024-03-27	Official Version Change V <sub>IN</sub> =1.2V to 1.0V	Tugz	Luh	Liujy
1.1	2024-07-12	Update I <sub>RC_VOUT</sub> Condition & Type Data	Tugz	Luh	Liujy